Docket No. 034299-624

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE 0 2 MAR 2005

APPLICANT:

François Templier, et al.

SERIAL NO.:

unassigned

CONFIRMATION No.: unassigned

FILING DATE:

herewith

TITLE:

Quasi-Vertical Power Semiconductor Device on a Composite Substrate

EXAMINER:

unassigned

ART UNIT:

unassigned

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

PATENT PRACTITIONERS TO BE MADE OF RECORD

Please recognize the following <u>ten</u> patent practitioners in the attached Declaration and Power of Attorney as being of record in the application or patent to which the power of attorney is directed:

Robert E. Krebs, Reg. No. 25,885 Marc S. Hanish, Reg. No. 42,626 John P. Schaub, Reg. No. 42,125 Thierry K. Lo, Reg. No. 49,097 Masako Ando, (37 C.F.R.§10.9 (b)) Yukiko Maekawa, Reg. No. 50,307 Khaled Shami, Reg. No. 38,745 Adrienne Yeung, Reg. No. 44,000 William Winters, Reg. No. 42,232 Hal J. Bohner, Reg. No. 27,856

The Commissioner is hereby authorized to charge any additional fees or credit any overpayment to Deposit Account No. 50-1698.

Respectfully submitted, THELEN REID & PRIEST LLP

Robert E. Krebs, reg. no. 25,885

Dated:

THELEN REID & PRIEST LLP

P.O. Box 640640

San Jose, CA 95164-0640 Telephone: (408) 292-5800

Fax: (408) 287-8040

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Declaration, Power Of Attorney and Petition

Page 1 of 3

WE (I) the undersigned inventor(s), hereby declare(s) that:

My residence, post office address and citizenship are as stated below next to my name,

We (I) believe that we are (I am) the original, first, and joint (sole) inventor(s) of the subject matter which is claimed and for which a patent is sought on the invention entitled

QUASI-VERTICAL POWER SEMICONDUCTING DEVICE ON COMPOSITE SUBSTRATE

the specification of whic	h						
is attached hereto.							
was filed on							
as Application Serial No.							
	and amended on						
was filed as PCT international application							
Number PCT/FR03/50045							
on September 1 st , 2003							
and was amended under PCT Article 19							
on							
				·.			
We (I) hereby state that we (I) have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.							
We (I) acknowledge the duty to disclose information known to be material to the patentability of this application as defined in Section 1.56 of Title 37 Code of Federal Regulations.							
We (I) hereby claim foreign priority benefits under 35 U.S.C. § 119 (a)-(d) or § 365 (b) of any foreign application(s) for patent or inventor's certificate, or § 365 (a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed. Prior Foreign Application (s)							
				Priority			
Application N	o.	Country	Day/month/Year	Claimed			
02 10883		FRANCE	03 September 2002	☐ YES ☐ NO			

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Page 2 of 3 Declaration

We (I) hereby claim the benefit under Title 35 application(s) listed below.	, United States Code, § 119	(e) of any United States prov	isional
(Application Num	mber)	(Filing Date)	
(Application Nun	nber)	(Filing Date)	
We (I) hereby claim the benefit under 35 International application designating the United Sthis application is not disclosed in the prior Unite paragraph of 35 U.S.C. § 112, I acknowledge the CFR § 1.56 which became available between the date of this application.	States, listed below and, inso ed States or PCT Internation duty to disclose information	ofar as the subject matter of a nal application in the manner which is material to patental	each of the claims of provided by the first pility as defined in 37
Application Serial No.	Filing Date	\ 1	ding, patented, ndoned)
And we (I) hereby appoint: Robert E. Krebs, S. Hanish, Registration No. 42,626; John P. Sc 43,186; Adrienne Yeung, Registration No. 44,000 No. 49,097; William Samuel Niece, Registration (my) attorneys of record with full power of subusiness in the United States Patent and Trad correspondence regarding this application be se Address is: P.O. Box 640640, San Jose, CA 9510 We (I) declare that all statements made here information and belief are believed to be true; at false statements and the like so made are punishal United States Code and that such wilful false statements.	chaub, Registration No. 42, 0; Steven J. Robbins, Regist in No.: P47,824; and John Hubstitution and revocation, illemark Office connected the ent to the firm of THELE1 64-0640. The property of the property	125; Gerhard W. Thielman, ration No. 40,299; Thierry K Klaas Uilkema, Registration to prosecute this application herewith; and we (I) hereby N REID & PRIEST LLP were are true and that all stants were made with the known or both, under Section 1001	Registration No. Lo, Registration No. 20,282; our and transact all request that all those Post Office tements made on yledge that willful of Title 18 of the
TEMPLIER François NAME OF FIRST SOLE INVENTOR Signature of Inventor February 1st, 2005 Date	3 5 5 0 Citizen o	o voinon F	RANCE EFLX residence

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DI CIOCCIO Léa NAME OF SECOND INVENTOR Signature of Inventor February 1st, 2005 Date	Residence: 418 Chemin de lahi 38 330 Saciel Hamier FRANCE Citizen of: FRANCE Post Office Address: The same as residence
NAME OF THIRD INVENTOR Signature of Inventor February 1st, 2005 Date	Residence: 292 Rue du Parc de La Sure 38 500 COUBLEVIE FRANCE Citizen of: FRANCE Post Office Address: The same as residence
NAME OF FOURTH INVESTOR Signature of Inventor February 1st, 2005 Date NAME OF FIFTH INVENTOR Signature of Inventor	Residence: 33, quai Jougland Scoo GRENCE FRANCE Citizen of: FRANCE Post Office Address: The same as residence Citizen of: Post Office Address: The same as residence